TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

## 2SA1430

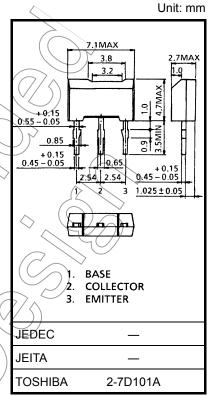
Strobe Flash Applications

Medium Power Amplifier Applications

- High DC current gain and excellent hFE linearity
  - :  $h_{FE}(1) = 140$  to 600 ( $V_{CE} = -1$  V,  $I_{C} = -0.5$  A)
  - :  $h_{FE}$  (2) = 60 (min), 120 (typ.) ( $V_{CE}$  = -1 V,  $I_{C}$  = -4 A)
- Low saturation voltage: VCE (sat) = -0.5 V (max) (IC = -2 A, IB = -50 mA)

## Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		$V_{CBO}$	-20	\ \ \	
Collector-emitter voltage		V <sub>CES</sub>	-20	V	
		V <sub>CEO</sub>	10/-		
Emitter-base voltage		V <sub>EBO</sub>	6	$\langle$	
Collector current	DC	lc (	-2	A	
	Pulsed	ICP	-4		
	(Note 1)	ICP	) <del>'</del>		
Base current		(IB <	-2	A	
Collector power dissipation		Pc	1000	mW	
Junction temperature		7/⟨\Tj	150	ŷ	
Storage temperature ran	ge		-55 to 150	ွဲ သ	



Weight: 0.2 g (typ.)

Note 1: Pulse width = 10 ms (max), duty cycle = 30% (max)

Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

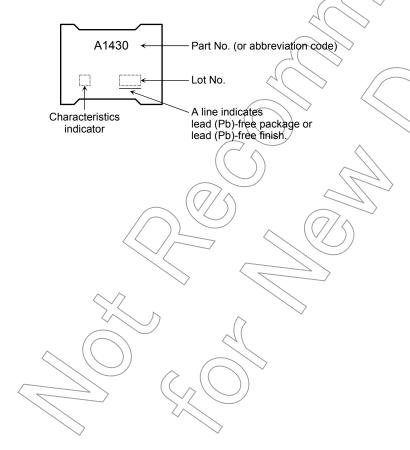
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## Electrical Characteristics (Ta = 25°C)

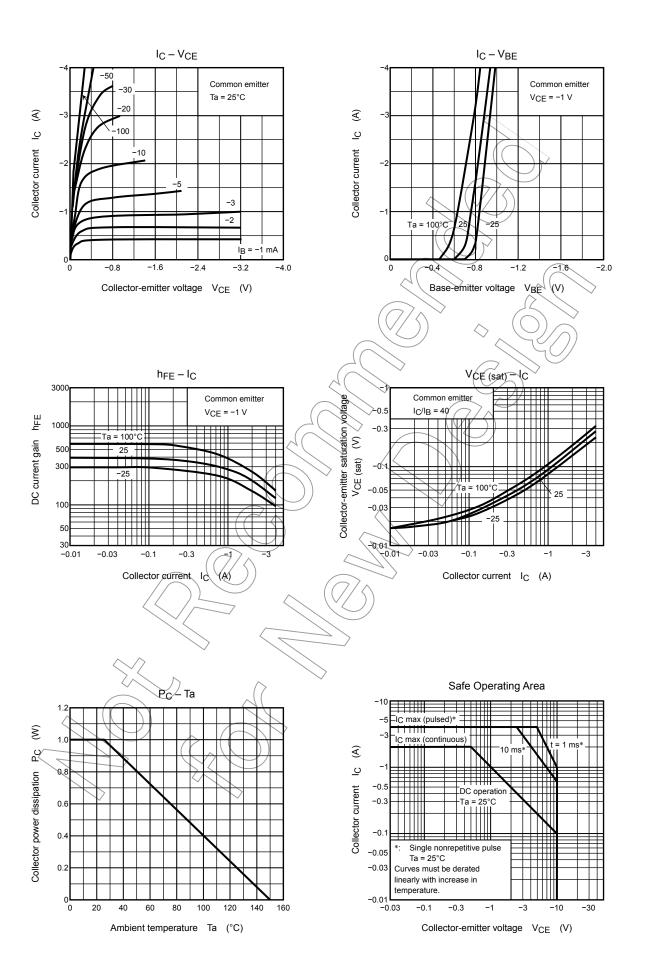
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -20 \text{ V}, I_E = 0$	_	_	-100	nA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = -6 V, I <sub>C</sub> = 0	_	_	-100	nA
Collector-emitter breakdown voltage	V (BR) CEO	$I_C = -10 \text{ mA}, I_B = 0$	-10	_	-	٧
Emitter-base breakdown voltage	V (BR) EBO	$I_E = -1 \text{ mA}, I_C = 0$	<u>-6</u>	_	_	V
DC current gain	h <sub>FE (1)</sub> (Note 3)	V <sub>CE</sub> = -1 V, I <sub>C</sub> = -0.5 A	140	)_	600	
	h <sub>FE (2)</sub>	V <sub>CE</sub> = -1 V, I <sub>C</sub> = -4 A	60	120	_	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	$I_C = -2 \text{ A}, I_B = -50 \text{ mA}$	_	-0.20	-0.50	V
Base-emitter voltage	V <sub>BE</sub>	V <sub>CE</sub> = -1 V, I <sub>C</sub> = -2 A	_	-0.83	-1.5	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = -1 V, I <sub>C</sub> = -0.5 A	_	140	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0, f = 1 MHz		<b>5</b> 0	$\rightarrow$	pF

Note 3: h<sub>FE (1)</sub> classification A: 140 to 280, B: 200 to 400, C: 300 to 600





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